

iMCP HT32SX V2.2 – SiP Sigfox

Sigfox® Monarch RF Transceiver System-in-Package

OVERVIEW

The iMCP - HT32SX is a Multicomponent Integrated Circuit (MCO) designed to provide a ready-to-use connectivity solution for Internet of Things (IoT) applications. It provides both uplink (transmit) and downlink (receive) communications, and it is the first HT Micron product in a new family of non-memory components. Its small dimensions, high performance and low power consumption targets the best experience for IoT developers. It features an ARM Cortex M0+ 32bit (STM32L052x8) and the S2-LP low power transceiver from ST Microelectronics combined with the SKY66420 from Skyworks Solutions which provide all the performance advantages, integration, and convenience of advanced semiconductor packaging technology into a single chip. Please check if you have the most updated version of this document by downloading it from THIS repository.

FEATURES

- Key features
 - Enables operations in the SIGFOX™ network
 - Multizone worldwide operation MONARCH
 - ARM Cortex M0+ 32bit STM32L052x8 MCU
 - Integrated 50 MHz crystal
 - 64 KB flash
 - 8 KB RAM
 - TX output power up to +24 dBm
 - RX sensitivity: -128 dBm
- Power consumption
 - 18 mA RX
 - 210 mA TX peak current @22 dBm on Sigfox message transmission
 - Max. of 26 dBm TX peak output power on Sigfox message transmission
- RF
 - S2-LP Transceiver STMicroelectronics
 - SKY66420-11 Front-End Module
 - Frequency bands:
 - o 413-479 MHz
 - o 452-527 MHz
 - o 826-958 MHz
 - o 904-1055 MHz
 - Modulation schemes:
 - o DBPSK, 2(G)FSK, OOK, ASK
 - o Sigfox data rate, up to region:
 - 100bps or 600bps





INTERFACES

- Up 21 General-Purpose Input/Output (GPIO) pins, with configurable pull-up/pull-down resistors
- 12-bit ADC
- 12-bit 1 channel DAC
- 2 USART, LPUART, USB 2.0, I2C
- Single power supply: 2.7 V to 3.6 V
- Operating temperature range: -40°C to +85°C
- External antenna
- 13x13x1.1mm LGA 32 pads package
- Part number: HTSXMO32L-22

APPLICATIONS

- Smart home
- Wireless alarm systems
- Manufacturing
- Agriculture
- Building automation
- Smart metering
- Smart lighting systems
- Smart grid monitoring

SUMMARY

C	OVERVIEW	2
SI	UMMARY	3
D	DOCUMENT INFO	3
1	BLOCK DIAGRAM	4
2	PINOUT INFORMATION	5
	2.1 PIN DIAGRAM	
	2.2 PIN DESCRIPTION	5
3	B ELECTRICAL CHARACTERISTICS	7
	3.1 GENERAL OPERATING RANGE	
	3.2 MCU I/O PORT CHARACTERISTICS	
	3.3 POWER CONSUMPTION	
	3.5 EXTERNAL CLOCK RESONATOR	
4	RF CHARACTERISTICS	10
•	4.1 EXTERNAL IMPEDANCE MATCHING NETWORK	
5	PACKAGE OUTLINE	11
6	RECOMMENDED PCB FOOTPRINT	12
7	PART NUMBER	12
8	PACKING AND ORDERING INFORMATION	13
9	STORAGE AND HANDLING	14
1	0 SOLDERING INFORMATION	14
D	DISCLAIMER	15
Α	ABBREVIATIONS	16
LI	.IST OF FIGURES	17
LI	.IST OF TABLES	17
R	REVISION HISTORY	18
С	CONTACT	18
D	OCCUMENT INFORMATION	18

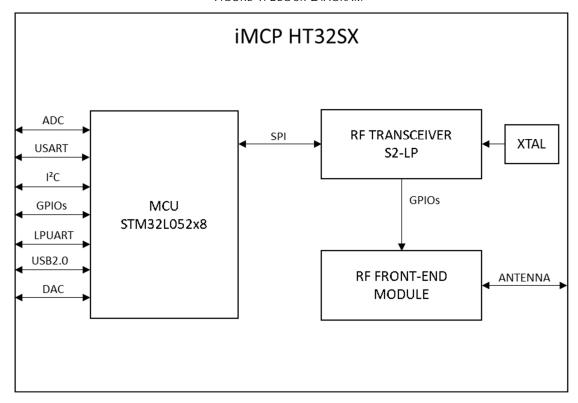
DOCUMENT INFO

This document provides information about iMCP HT32SX - Sigfox® Monarch RF Transceiver System-in-Package. Make sure you have the most up-to-date information about this product at https://github.com/htmicron/ht32sx.

1 BLOCK DIAGRAM

Functional description.

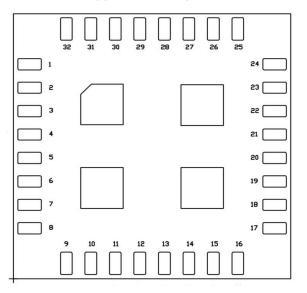
FIGURE 1: BLOCK DIAGRAM



2 PINOUT INFORMATION

2.1 Pin Diagram

FIGURE 2: PIN DIAGRAM



2.2 Pin description

TABLE 1: LEGEND/ABBREVIATIONS USED IN PIN DESCRIPTION TABLE

Name	Abbreviation	Definition
	FT	5V tolerant I/O
	FTf	5V tolerant I/O, FM+ capable
I/O Structure	TC	Standard 3.3V I/O
	В	Dedicated BOOT0 pin
	RST	Bidirectional reset pin with embedded weak pull-up resistor

TABLE 2: PIN DESCRIPTION

Number	Symbol	Pin name	Pin Type	I/O Structure	Description
1	ANTENNA	ANTENNA	RF I/O	-	RF input and output signal
2	GND	GND	Ground		Exposed pad connected to the ground of
	GIVD	GND	Ground	-	the application board
		USART1_CTS	Digital I/O		USART interface
9	MCU-PA11 USB_DM COMP1_OUT EVENT_OUT	Digital I/O	FT	USB	
3		COMP1_OUT	Analog O		Comparator output
		EVENT_OUT	Digital I/O		
4	MCU-PA9	USART1_TX	Digital I/O	FT	Serial wire
5	MCU-PA10	USART1_RX	Digital I/O	FT	Seriai Wille
		LPUART1_RX	Digital I/O		Low-power USART interface
6	MCU-PB11	TIM2_CH4	Digital I/O	FT	General-purpose timer
		EVENTOUT	Digital I/O		
7	MCU-PB0	ADC_IN8	Analog I	FT	ADC external input 8
	IVICU-PBU	VREF_OUT	Analog I/O	ГІ	Output reference voltage

8	VDD_3.3V	VDD_3.3V	Power	_	3.3 V power supply
	VBB_6.6 V	USART1_CK	Digital I/O		USART interface
9	MCU-PA8	USB_CSR_SYNC	Digital I/O	FT	USB
		EVENT_OUT	Digital I/O		
		ADC_IN5	Analog I		ADC external input 5
40	MOLLDAG	TIM2_CH1	Digital I/O	T-0	General-purpose timer
10	MCU-PA5	TIM2_ETR	Digital I/O	TC	General-purpose timer
		COMP1_INM5	Analog I		Comparator input
		USART2_RX	Digital I/O		USART interface
11	MCU-PA3	ADC_IN3	Analog I	FT	ADC external input 3
11	MCU-PA3	TIM2_CH4	Digital I/O	г	General-purpose timer
		TIM21_CH2	Digital I/O		General-purpose timer
		USART2_RTS_DE	Digital I/O		USART interface
		ADC_IN1	Analog I		ADC external input 1
12	MCU-PA1	COMP1_INP	Analog I	FT	Comparator input
		TIM21_ETR	Digital I/O		General-purpose timer
		EVENT_OUT	Digital I/O		
13	MCU-PB10	LPUART1_TX	Digital I/O	FT	USART interface
13	IVICO-FBTO	TIM2_CH3	Digital I/O	1 1	General-purpose timer
		LPUART1_CTS	Digital I/O		USART interface
	MCU-PA6	ADC_IN6	Analog I		ADC external input 6
14		TIM22_CH1	Digital I/O	FT	General-purpose timer
		COMP1_OUT	Analog O		Comparator output
		EVENT_OUT	Digital I/O		
	MCU-PA4	USART2_CK	Digital I/O		USART interface
		ADC_IN4	Analog I		ADC external input 4
15		DAC_OUT	Analog O	TC	DAC analog output
		TIM22_ETR	Digital I/O		General-purpose timer
		COMP1_INM4	Analog I		Comparator input
16	GND	GND	Ground	-	Exposed pad connected to the ground of
					the application board
		USART2_TX	Digital I/O		USART interface
17	MCU-PA2	ADC_IN2	Analog I	FT	ADC external input 2
		TIM21_CH1	Digital I/O		General-purpose timer
		TIM2_CH3	Digital I/O		General-purpose timer
		WKUP1	Digital I		MCU external wakeup input
18	MCU-PA0	ADC_IN0	Analog I	TC	ADC external input 0
		USART2_CTS	Digital I/O	_	USART interface
	14011	TIM2_CH1	Digital I/O		General-purpose timer
19	MCU- BOOT0	BOOT0	Digital I	В	Boot selection
		I2C1_SMBA	Digital I/O		I2C interface
20	MCU-PB5	LPTIM1_IN1	Digital I/O	FT	Low-power timer
		TIM22_CH2	Digital I/O		General-purpose timer
21	GND	GND	Ground	-	Exposed pad connected to the ground of the application board
22	NRESET	NRESET	I/O	RST	Bidirectional reset pin with embedded weak pull-up resistor
		SWCLK	Digital O		Serial wire clock output
23	MCU-PA14	USART2_TX	Digital I/O	- FT	USART interface
		SWDIO	Digital I/O		Serial wire
24	MCU-PA13	USB_NOE	 Digital I/O	- FT	USB

25	MCU-PC15	OSC32OUT	Ext. clock	- TC	External clock source pins
25	WICO-FC15	GPIO	Digital I/O	TC TC	General purpose I/O
26	MCU DC14	OSC32IN	Ext. clock	- FT	External clock source pins
20	MCU-PC14	GPIO	Digital I/O	FI	General purpose I/O
27	GND	GND	Ground	-	Exposed pad connected to the ground of the application board
		LPUART1_RTS_DE	Digital I/O		Low-power USART interface
28	MCU-PB1	ADC_IN9	Analog I	FT	ADC external input 9
		VREF_OUT	Analog O	11	1.2 V VCO-LDO band-gap reference voltage decoupling
	MCU-PB7	USART1_RX	Digital I/O		USART interface
29		I2C1_SDA	Digital I/O	FTf	I2C interface
		LPTIM1_IN2	Digital I/O		Low-power timer
		USART1_TX	Digital I/O		USART interface
30	MCU-PB6	I2C1_SCL	Digital I/O	FTf	I2C interface
		LPTIM1_ETR	Digital I/O		Low-power timer
		USART1_RTS_DE	Digital I/O		USART interface
31	MCU-PA12	USB_DP	Digital I/O	FT	USB
		EVENT_OUT	Digital I/O		
32	GND	GND	Ground	-	Exposed pad connected to the ground of the application board

3 ELECTRICAL CHARACTERISTICS

3.1 General operating range

TABLE 3: GENERAL OPERATING RANGE

Parameter	Conditions	Min	Тур.	Max	Unit
Supply voltage	-	2.7	3.3	3.6	V
Operating temperature	-	-30	25	85	°C
Storage temperature			Refer to section	9	

3.2 MCU I/O port characteristics

TABLE 4: MCU I/O PORT CHARACTERISTICS

Symbol	Parameter	Conditions	Min	Тур.	Max	Unit
v	Input low level	Input low level TCFT, FTf, RST I/Os		-	0.3V _{DD}	
V_{IL}	voltage	BOOT0 pin	-	-	0.14V _{DD}	
V_{IH}	Input high level voltage	All I/Os	0.7 V _{DD}	-	-	V
V	I/O Schmitt trigger voltage hysteresis	Standard I/Os	-	10% V _{DD}	-	
V_{hys}		BOOT0 pin	-	0.01	-	
ī	Input leakage	$V_{SS} < V_{IN} < V_{DD}$ All I/Os except PA11, PA12, BOOT0, FTf I/Os	-	-	+-50	200
\mathbf{I}_{lkg}	current	$V_{SS} < V_{IN} < V_{DD}$ PA11 and PA12 I/Os	-	-	-50/+250	- nA

		$V_{SS} < V_{IN} < V_{DD}$ FTf I/Os	-	-	+-100	
		$V_{VDD} < V_{IN} < 5V$ All I/Os except PA11, PA12, BOOT0, FTf I/Os	-	-	200	
		$V_{SS} < V_{IN} < 5V$ FTf I/Os	-	-	500	nA
		V _{SS} < V _{IN} < 5V PA11, PA12, BOOT0	-	-	10	uA
R_{PU}	Weak pull-up equivalent resistor	$V_{IN} = V_{SS}$	25	45	65	kΩ
R_{PD}	Weak pull-down equivalent resistor	$V_{IN} = V_{DD}$	25	45	65	kΩ
C_{IO}	I/O pin capacitance	-	-	5	-	pF

TABLE 5: OUTPUT VOLTAGE CHARACTERISTICS

Symbol	Parameter	Conditions	Min	Max	Unit
V_{OL}	Output low level voltage for an I/O pin	CMOS port $I_{IO} = +8\text{mA}$	-	0.4	
V_{OH}	Output high level voltage for an I/O pin	$2.7V < V_{DD} < 3.6V$	V _{DD} -0.4	-	
V_{OL}	Output low level voltage for an I/O pin	TTL port I_{IO} =+8mA 2.7V <v<sub>DD< 3.6V</v<sub>	-	0.4	
V_{OH}	Output high level voltage for an I/O pin	TTL port $I_{IO} = -6\text{mA}$ $2.7\text{V} < \text{V}_{DD} < 3.6\text{V}$	2.4	-	
V_{OL}	Output low level voltage for an I/O pin	I_{IO} = +15mA 2.7V < V_{DD} < 3.6V	-	1.3	V
V_{OH}	Output high level voltage for an I/O pin	I_{IO} = -15mA 2.7V <v<sub>DD< 3.6V</v<sub>	V _{DD} -1.3	-	
V_{OL}	Output low level voltage for an I/O pin	I_{IO} =+4mA 2.7V <v<sub>DD< 3.6V</v<sub>	-	0.45	
V_{OH}	Output high level voltage for an I/O pin	I_{IO} = -4mA 2.7V <v<sub>DD< 3.6V</v<sub>	V _{DD} -0.45	-	
\mathbf{V}_{OLFM+}	Output low level	I_{IO} = +20mA 2.7V < V_{DD} < 3.6V	-	0.4	
	voltage for an FTf I/O pin in FM+ mode	I_{IO} = 10mA 2.7V <v<sub>DD< 3.6V</v<sub>	-	0.4	

3.3 Power consumption

Characteristics measured over recommended operating conditions unless otherwise specified. Typical values are referred to 25 °C temperature, VDD = 3.3 V.

Table 6: Low-power state power consumption TA = 25 °C, VDD = 3.3 V.

Parameter	Conditions	Min	Тур.	Max	Unit
	Shutdown	-	-	-	nA
C	Standby	1.3	1.33	1.4	mA
Supply current	Sleep	2.67	5.5	9.2	uA
	Deep sleep	2.5	3.5	8.4	uA

TABLE 7: POWER CONSUMPTION IN RECEPTION TA = 25 °C, VDD = 3.3 V, FC = 905 MHZ

Parameter	Conditions	Min	Тур.	Max	Unit
Supply current	RX @ -128 dBm sensitivity level for a	-	18	-	mA
	Sigfox signal				

Table 8: Power consumption in transmission TA = 25 °C, VDD = 3.3 V, FC = 902.2 MHz

Parameter	Conditions	PA	Min	Тур.	Max	Unit
Average supply current of a	TX @22 dBm	ON	148	170	190	
single Sigfox frame	TX @12 dBm	OFF	19.2	25	27	
Average supply current of a	TX @26 dBm	ON	-	160	-	
Sigfox message	TX @22 dBm	ON	-	110	-	mA
(total of 3 frames)	TX @12 dBm	OFF	-	21.5	-	
Peak supply	TX @26 dBm	ON	-	-	313	
current on Sigfox message	TX @22 dBm	ON	-	-	210	
transmission	TX @12 dBm	OFF	-	-	28.5	

3.4 Internal crystal oscillator

The integrated crystal oscillator is used as the frequency reference for the RF transceiver and its choice was based on the Sigfox requirements.

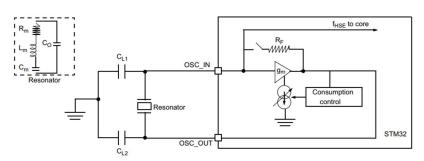
TABLE 9: 50 MHz INTERNAL XTAL CLOCK SOURCE CHARACTERISTICS

Parameter	Conditions	Min	Тур.	Max	Unit
Nominal frequency	-	-	50	-	MHz
Frequency tolerance	-20°C to 75 °C	-10	-	+10	ppm

3.5 External clock resonator

The external clock resonator can be of high speed (1-25MHz) or low speed (32.768kHz), which can be connected to pins 25 and 26 of the iMCP HT32SX V2.2. The connection diagram is shown below. For CL1 and CL2, it is recommended to use high quality ceramic capacitors in the 5pF to 25 pF range (typ.), designed for high frequency applications, and selected to match the requirements of the crystal or resonator. These capacitors are usually of equal value with a rough estimate of 10 pF each. CL1 and CL2 includes PCB and the MCU pin capacitances.

FIGURE 3: EXTERNAL OSCILLATOR CIRCUIT DIAGRAM.



4 RF CHARACTERISTICS

Table 10: Transceiver and Receiver Characteristics. TA = 25°C based on Characterization; not tested in production. VDD = 3.3V; All RX measurements made at the antenna connector, to a bit error rate (BER) limit of 1%.

Parameter		Min	Тур.	Max	Unit
	TX	865	-	924	MHz
RF Frequency	RX	869	-	923	MHz
Tx max. output pow	Tx max. output power for the Sigfox signal		24	-	dBm
Emission 2 nd Harmonic (conducted) @max power		-40.4	-47.3	-39.9	
Emission 3 rd Harmonic (conducted) @max power		-50.5	-76.2	-55.0	dBc
Emission 4 th harmonic (conducted) @max power		-78.9	-78.6	-70.0	
Data Rate	TX (RC1, RC3, RC5, RC6, RC7)	-	100	-	bps
(for Sigfox	TX (RC2, RC4)	-	600	-	bps
Regions)	RX (All RCs)	-	600	-	bps
Antenna Lo	Antenna Load Impedance		50		Ohm
Rx Sensitivity (@600bps, GFSK)			-128		dBm
Rx Spurious Emission (30MHZ~12.75GHZ)		-	-	-	dBm
Rx Blocking at 10MHz offset		-	-	-	dB
RSSI Resolution		-	-	-	dB

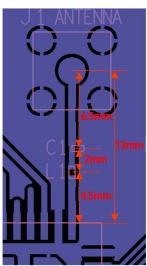
4.1 External impedance matching network

An external LC matching network is recommended to improve the output power level of the output signal in pin 1 (series inductor and shunt capacitor). The reference specifications for a reference FR4 1.6 mm 1 Oz copper printed circuit board (PCB) are shown below.

- SMD ceramic inductor: 5.6 nH, +-5% tolerance, 0402 size, PN L-07C5N6SV6, Johanson Technologies
- SMD ceramic capacitor: 4.7 pF, +-0.1pF tolerance, 0201 size, PN 250R05L4R7BV4S, Johanson Technologies

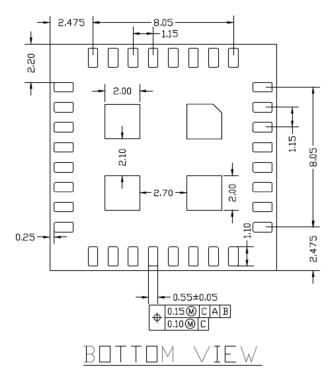
The reference PCB traces are shown in Figure 4 for an example of an output using an SMA connector. The trace width are the same as the pad width in the recommended footprint in section 6.

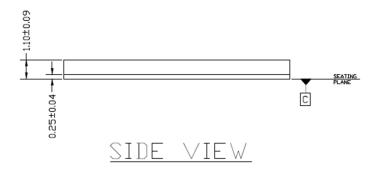
Figure 4: Recommended external LC matching network layout.



5 PACKAGE OUTLINE

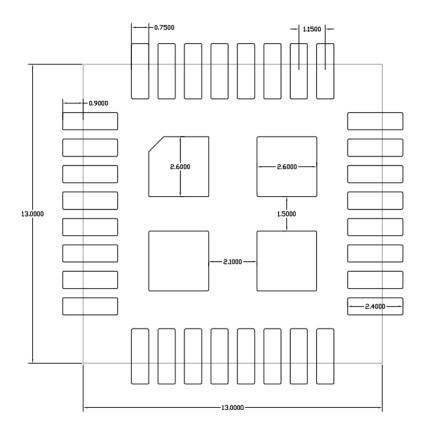
FIGURE 5: PACKAGE OUTLINE



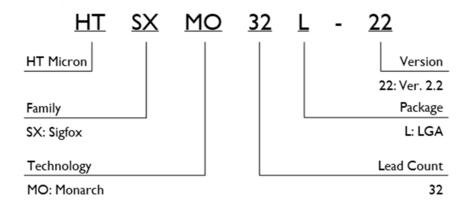


6 RECOMMENDED PCB FOOTPRINT

FIGURE 6: RECOMMENDED PCB FOOTPRINT



7 PART NUMBER



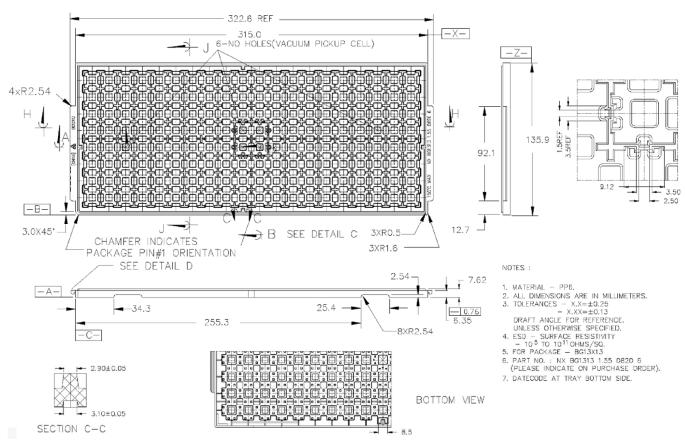
8 PACKING AND ORDERING INFORMATION

TABLE 11: ORDERING INFORMATION

	Package			
Part number	Name	Description	Version	
HTSXMO32L-22	iMCP HT32SX	SiP module in LGA package; body 13mm x 13mm	2.2	

Products sold directly by HT Micron will be delivered in bagged trays, sealed in moisture resistant bags with desiccant pack and humidity cards. Trays are suitable for baking temperatures. Samples provided by HT Micron may be delivered in other packing methods. Please, refer to section 9 for storage, handling and moisture sensitivity information.

FIGURE 7: TRAY SIZES



9 STORAGE AND HANDLING



CAUTION

ELECTROSTATIC and MOISTURE SENSITIVE DEVICE



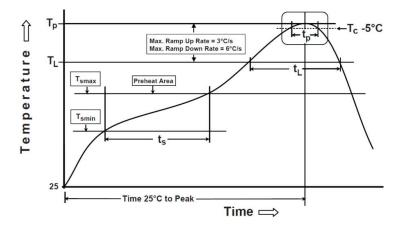
LEVEL 3

- Baking for 24 hours at 125 ±5°C is strongly recommended prior to mounting.
- Take proper precautions to avoid high-energy electrostatic discharge (ESD) as permanent damage may occur.
- For handling methods refer to the latest ESD Association standard ANSI/ESD S20.20.
- Do not expose the device to corrosive gasses, extreme humidity, extensive direct sunlight.
- The device is susceptible to delamination or crack damage induced by absorbed moisture and high temperature.
- Shelf life in sealed bagged tray: 12 months at ≤40°C and ≤90% relative humidity (RH).
- This device is rated MSL 3.
- For bagged tray lots: after the bag is opened, the humidity card must read ≤20% (at 23 ±5°C), and the devices must be mounted within 168 hours at environmental conditions of ≤30°C, ≤60% RH.
- If the above condition is not met, baking for 24 hours at 125 ±5°C is mandatory prior to mounting.
- For moisture sensitivity devices precaution methods refer to the latest standard IPC/JEDEC-J-STD-033.
- For any other packing method: baking is required for 192 hours at 40°C prior to mounting.
- This device is composed of all RoHS compliant materials. Refer to the Figure 8 for typical Pb-Free reflow conditions.
- Hand soldering is not recommended for this device.
- For moisture sensitivity classification and soldering methods, refer to the latest standard IPC/JEDEC-J-STD-020.
- Do not drop, shock or apply mechanical stress.

10 SOLDERING INFORMATION

Soldering conditions depend greatly on the solder paste that is used and as such are application specific. The picture below depicts typical Pb-free soldering conditions as seen in IPC/JEDEC-J-STD-020 standard, which are commonly used in the industry. However, ultimately, we recommend that the instructions of the solder supplier are followed.

FIGURE 8: TYPICAL PB-FREE REFLOW CONDITIONS (IPC/JEDEC-J-STD-020)



- Min preheat temperature (T_{smin}): 150 °C
- Max preheat temperature (T_{smax}): 200 °C
- Preheat (soaking) time (T_s): 60 to 120 s
- Liquidous temperature (T_L): 217 °C
- Peak temperature (Tp): 260 °C
- Max ramp-up rate (T₁ to T_p): 3 °C/s
- Time above T_L (t_L): 60 to 150 s
- Classification temperature (T_c): 260 °C
- Time above Tc -5 °C (t_p): 30 s
- Max ramp-down rate (Tp to TL): 6 °C/s
- Max time 25°C to T_p: 8 minutes

DISCLAIMER

This document in a property of HT Micron and cannot be reproduced without its consent. Information herein contained are for informational purposes only and HT Micron assumes no responsibility for errors or omissions in this document. HT Micron documents, products, product specifications and descriptions may change without notice, at any time. Purchasers should obtain the latest relevant information on HT Micron products before placing orders.

HT Micron assumes no liability for customer product applications, design or damage to any equipment resulting from the use of HT Micron products outside of specifications and parameters.

No license of any patent, copyright or any other intellectual property right is granted by this document, whether by implication, estoppel or otherwise. HT Micron assumes no liability for any materials, products or information provided in this document except as may be provided in Terms and Conditions of Sale for customers purchasing directly from HT Micron.

Products, specifications and information are provided on an "as is" basis for reference purposes only and without warranties of any kind. HT Micron does not warrant the accuracy or completeness of information contained in this document.

HT Micron products are not intended for use in life support, medical care, safety equipment, or any other application in which product failure could lead to loss of life, personal injury, physical or environmental damage.

ABBREVIATIONS

TABLE 12: ABBREVIATIONS

Acronym	Description		
ADC	Analog to Digital Converter		
AES	Advanced Encryption Standard		
API	Application Program Interface		
CLK	Clock		
EEPROM	Electrically-Erasable Programmable Read Only Memory		
FIFO	First in First Out		
GPIO	General Purpose Input Output		
ID	Identification		
IF	Intermediate frequency		
Ю	Input Output		
MSL	Moisture sensitivity level		
PCB	Printed-Circuit Board		
PHY	Physical		
SPI-bus	Serial Peripheral Interface -bus		
PWM	Pulse Width Modulation		
RAM	Random Access Memory		
RC	Remote Control		
RF	Radio Frequency		
RoHS	Restriction of Hazardous Substances		
RSSI	Receive Signal Strength Indication		
RX	Receiver		
SCL	Serial Clock		
SDA	Serial Data		
TX	Transmitter		

17/18

LIST OF FIGURES

Figure 1: Block Diagram	4
Figure 1: Block DiagramFigure 2: Pin Diagram	5
Figure 3: External oscillator circuit diagram	9
Figure 4: recommended external LC matching network layout	11
Figure 5: Package Outline	11
Figure 6: Recommended PCB Footprint	12
igure 7: Tray sizes	13
Figure 8: Typical Pb-Free reflow conditions (IPC/JEDEC-J-STD-020)	14
LIST OF TABLES	
Table 1: Legend/abbreviations used in pin description table	5
Table 2: Pin description	
Table 3: General Operating RangeRange	
Table 4: MCU I/O port characteristics	7
Table 5: Output voltage characteristics	
Table 6: Low-power state power consumption TA = 25 °C, VDD = 3.3 V	
Table 7: Power consumption in reception TA = 25 °C, VDD = 3.3 V, fc = 905 MHz	
Table 8: Power consumption in transmission TA = 25 °C, VDD = 3.3 V, fc = 902.2 MHz	9
Table 9: 50 MHz Internal XTAL clock source characteristics	9
Table 10: Transceiver and Receiver characteristics. TA = 25°C based on characterization; not tested in production. VDD = 3.3V	; All RX
measurements made at the antenna connector, to a bit error rate (BER) limit of 1%	
Table 11: Ordering information	
Table 12: Abbreviations	16

REVISION HISTORY

Date	Version	Changes	
13/04/2020	00	- Initial draft	
05/08/2020	01	- Preliminary	
20/11/2020	02	- Preliminary - fixed power consumption information	
25/01/2021	03	- Fixed ADC_IN8 (PB0) on PIN7, operating temperature range update	
19/02/2021	04	- Package height; packing; storage, handling and soldering; disclaimer	
24/03/2021	05	- Current supply updates.	
14/12/2021	06	- Preliminary mark removed.	
11/02/2022	2 07	-Device temperature range, Handling and Storage section and datasheet web link	
		reference updated	

CONTACT

HT MICRON SEMICONDUTORES S.A. Av. Unisinos, 1550 | 93022-750 | São Leopoldo | RS | Brasil www.htmicron.com.br

DOCUMENT INFORMATION

Document Title: iMCP HT32SX V2.2 - SiP Sigfox

Document Subtitle: Sigfox® Monarch RF Transceiver System-in-Package

Classification: Public Doc. Type: DATASHEET

Revision: Rev. 07 Date: 14/12/2021 Code: DS001

Internal Doc Reference: FO440 - rev.01 Data: 12/08/2020 Doc. Ref.: PR001